AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Serial Number: 10/608,405

Filing Date: June 26, 2003

Title: COMPOSITE THERMAL INTERFACE DEVICES AND METHODS FOR INTEGRATED CIRCUIT HEAT TRANSFER

Assignee: Intel Corporation

IN THE CLAIMS

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Please amend the claims as follows:

1. (Original) A method of manufacturing a thermal interface device, comprising: placing a heat conducting structure on a first metal containing layer; attaching the first metal containing layer to the heat conducting structure; and attaching the first metal containing layer to a component surface; wherein, at least one attaching operation of the first metal containing layer includes plastic deformation of the first metal containing layer into surface features along a deforming interface at a temperature lower than a melting temperature of the first metal containing layer.

- 2. (Original) The method of claim 1, further including plastic deformation of the first metal containing layer at a temperature higher than ambient temperatures.
- 3. (Original) The method of claim 1, wherein placing the heat conducting structure on the first metal containing layer includes placing a heat conducting structure that covers a fraction of a side of the first metal containing layer.
- 4. (Original) The method of claim 1, wherein attaching the first metal containing layer to the heat conducting structure includes attaching an indium solder layer to the heat conducting structure.
- 5. (Original) The method of claim 1, further including attaching a second metal containing layer to the heat conducting structure substantially opposite the first metal containing layer.
- 6. (Original) The method of claim 5, wherein attaching the second metal containing layer to the heat conducting structure includes attaching an indium solder layer to the heat conducting structure.

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7. (Original) The method of claim 5, further including selecting a different material for the first metal containing layer and the second metal containing layer.

- 8. (Currently Amended) The method of claim 1, wherein heat placing [[a]] the heat conducting structure on [[a]] the first metal containing layer includes placing a diamond film on [[a]] the first metal containing layer.
- 9. (Currently Amended) The method of claim 1, wherein heat placing [[a]] the heat conducting structure on [[a]] the first metal containing layer includes placing a heat conducting structure chosen from a group consisting of woven carbon fibers and pyrolized carbon.
- 10. (Original) The method of claim 1, wherein attaching the first metal containing layer to a component surface includes attaching the first metal containing layer to an integrated heat spreader surface.
- 11. (Original) The method of claim 1, wherein attaching the first metal containing layer to a component surface includes attaching the first metal containing layer to a integrated circuit chip surface.
- 12. (Original) A processor assembly, comprising:
 - a processor chip attached to a substrate;
 - a thermal interface device coupled to a surface of the processor chip, including:
 - a first metal containing layer;
- a second metal containing layer stacked over the first metal containing layer with a first side attached to the surface of the processor chip;
- a substantially planar carbon structure located between at least a portion of the first metal containing layer and the second metal containing layer; and

an integrated circuit package cover coupled to the first metal layer, the integrated circuit package cover substantially enclosing the processor chip and the thermal interface device within a volume on the substrate.

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13. (Original) The processor assembly of claim 12, wherein the substantially planar carbon structure completely separates the first metal containing layer and the second metal containing layer.

- 14. (Original) The processor assembly of claim 12, wherein the substantially planar carbon structure includes a diamond film.
- [[14]] 15. (Currently Amended) The processor assembly of claim 12, wherein the substantially planar carbon structure is chosen from a group consisting of woven carbon fibers and pyrolized carbon.
- [[15]] 16. (Currently Amended) The processor assembly of claim 12, wherein the first metal containing layer includes solder.
- [[16]] <u>17</u>. (Currently Amended) The processor assembly of claim 12, wherein the second metal containing layer includes solder.
- [[17]] 18. (Currently Amended) The processor assembly of claim 12, wherein the first metal containing layer and the second metal containing layer include substantially pure indium (In).
- [[18]] <u>19</u>. (Currently Amended) The processor assembly of claim 12, wherein the first metal containing layer is different from the second metal containing layer.
- [[19]] <u>20</u>. (Currently Amended) The processor assembly of claim 12, further including a heat sink coupled to the integrated circuit package cover.
- [[20]] 21. (Currently Amended) The processor assembly of claim 12, wherein at least one metal containing layer includes mechanical bond features at an interface.

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- [[21]] 22. (Currently Amended) An information handling system, comprising:
 - a non-volatile memory;
 - a system bus coupled to the non-volatile memory;
- a processor chip assembly coupled the system bus, the processor chip assembly including:
 - a processor chip attached to a substrate;
 - a thermal interface device coupled to a surface of the processor chip, including:
 - a first metal containing layer;
- a second metal containing layer stacked over the first metal containing layer with a first side attached to the surface of the processor chip;
- a substantially planar carbon structure located between at least a portion of the first metal containing layer and the second metal containing layer; and an integrated heat spreader coupled to the first metal containing layer
- [[22]] 23. (Currently Amended) The information handling system of claim [[21]] 22, wherein the first side of the second metal containing layer is attached to a backside of [[a]] the processor chip in flip-chip orientation.
- [[23]] <u>24</u>. (Currently Amended) The information handling system of claim [[21]] 22, wherein the non-volatile memory includes a flash memory.
- [[24]] <u>25</u>. (Currently Amended) The information handling system of claim [[21]] <u>22</u>, wherein the substantially planar carbon structure includes a diamond film.
- [[25]] <u>26</u>. (Currently Amended) The information handling system of claim [[21]] 22, wherein the first metal containing layer and the second metal containing layer include substantially pure indium (In) solder.
- [[26]] <u>27</u>. (Original) The information handling system of claim [[21]] 22, wherein at least one metal containing layer includes mechanical bond features at an interface.